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ARTICLE

Nanostructured 2D MoS₂ Honeycomb and Hierarchical 3D Marigold Nanoflower of CdMoS₄ for Hydrogen Production under Solar Light

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The unique two dimensional (2D) honeycomb layered MoS₂ nanostructure and hierarchical 3D marigold nanoflowers of CdMoS₄ were architected using a template free facile solvothermal method. The MoS₂ depicts the sheet like morphology with lateral dimension 5-10 μm and thickness ~ 200 nm with honeycomb nanostructure architecture via self-assembling of vertically grown thin hexagonal nanosheets with thickness 2-3 nm. The 3D architected CdMoS₄ marigold nanoflowers comprised with thin nano petals with lateral dimension 1-2 μm and thickness of few nm. The CdMoS₄ and MoS₂ were confer hydrogen (H₂) production rate, 25445 and 12555 μMoleh⁻¹g⁻¹, respectively. The apparent quantum yield of hydrogen production was observed to be 35.34 and 17.18 % for CdMoS₄ and MoS₂, respectively. The 3D nanostructure marigold flowers of CdMoS₄ and honeycomb like 2D nanostructure of MoS₂ responsible for higher photocatalytic activity due to inhibition in the charge carrier recombination. The prima fascia observation of H₂ production shows that the ternary semiconductor confers enhanced photocatalytic activity for H₂ generation due to unique structure. Such structures can be architecture and implemented for other transition metal dichalcogenide based ternary materials for enhanced photocatalytic and other applications.

1 Introduction

Transition metal dichalcogenides (TMDCs) such as 2D honeycomb like layered MoS₂ and other semiconductor nanostructure materials have immense importance due to their size and shape dependent enhanced properties for various energy and nanoelectronics device applications.¹⁻³ Significantly, 1 to 3D nanostructure materials have been widely utilized for the advance energy applications like solar cells, batteries, photocatalysis and for optoelectronic applications.³⁻⁶ Particularly, in photocatalysis the nanostructure semiconductors and especially hierarchical nanostructures are playing crucial role in the drastic enhancement in the efficiency due to the control on recombination of photo generated charge carriers.⁷

The H₂ is one of the best options for the future as a clean and direct fuel source to solve our energy related problems and need. Moreover, H₂ can be produced from several different sources such as water, biomass, natural gas or coal.⁸⁻¹⁰ Currently, the most commonly used and practically efficient methods for H₂ production are coal gasification and steam reforming of methane. But both the methods are energy rigorous with undesirable for environmental related issues and problems.^{8,11} The environment pollutant and corrosive H₂S is continuously released (10-15% as waste) by oil refineries is a global intimidation to the environment. The present Claus process is a commercial process for H₂S utilization to produce liquid sulphur rather than H₂ which is laborious and highly expensive.¹² Hence, the generation of clean H₂ energy from the

decomposition of abundant environmental pollutant H₂S has been more significance. The great challenge is to design a catalyst system that can electively use sunlight and H₂S to generate H₂. Heterogeneous photocatalysts plays an important role for the conversion of photon energy into chemical energy and for decomposing the organic contaminants as well as H₂ generation.^{13,14} There are reports on the development of ultra-violet active photocatalyst for H₂ production based on oxide nanomaterials.¹⁵⁻¹⁶ But the problem with oxide based catalyst such as TiO₂, ZnO, ZnO/ZnS, have wide band gap and show activity under UV light only (>3.0 eV) which is only 5% of the solar spectrum and did not show good photocatalytic activity in the visible light.^{17,18} Furthermore, there are attempts on development of doped oxide nanomaterials for visible light active photocatalyst such as Fe₂O₃, Bi₂O₃, BiVO₄, MoO₃, ZnCo₂O₄, N doped TiO₂/ZnO *etc.* for H₂ generation.¹⁸⁻²⁴ However, the problem with these materials is their poor stability. Hence, researchers are concentrating for the development of stable and visible light active efficient photocatalyst for H₂ production from water as well as H₂S. The visible light active semiconductor sulphide photocatalyst have been reported which includes, CdS, CuS, In₂S₃, Bi₂S₃ *etc.*^{13,25-29} Among all the sulfides photocatalyst, CdS was found to be good visible light active photocatalyst, but due to photocorrosion and stability of CdS limits its commercial use as a visible light active photocatalyst. Hence, further researchers have tried to develop hetero structures of CdS-ZnO, CdS-TiO₂ *etc.* as a visible light active photocatalyst for H₂ generation.³⁰⁻³¹

Recently, we have also investigated cadmium based ternary chalcogenide as a visible light active photocatalysts.³² These ternary systems observed to be efficient as compare to CdS and other sulfide. Further, we have also attempted H₂ generation via H₂S decomposition using nanostructure cadmium indium sulfide and zinc indium sulfide ternary semiconductor photocatalyst.³²⁻³⁴ The hierarchical nanostructures of such ternary systems are expected to be efficient photocatalyst due to the high surface area and large aspect ratio. Hence, we focused the innovative approach for the synthesis of such hierarchical nanostructures as a visible light active photocatalyst for H₂ production.

In this context, we have attempted to develop template free synthesis of ternary CdMoS₄ as well as pristine MoS₂ nanosheet with 2D honeycomb nanostructure by simple solvothermal method. Considering their optical properties, they have ability to be used as a visible light active photocatalyst for H₂ production from photocatalytic H₂S splitting. In the present investigation, we have demonstrated the synthesis of 3D hierarchical nanostructure marigold CdMoS₄ nanoflower and 2D MoS₂ honeycomb nano sheet as a photocatalyst for H₂ production from H₂S under solar light which is hitherto unattempted.

2. EXPERIMENTAL METHODS

2.1 Material Preparation

All chemicals were purchased from Fisher Scientific with (Purity 99 %). All the chemicals were analytic grade and were used without any further purification. Cadmium nitrate (2 mmol) dissolved in methanol (40-50 ml) and ammonium molybdate (20 ml) dissolved in methanol by addition of nitric acid drop by drop with constant stirring for 10 minutes as long as to see the clear solution. Next we followed the drop wise addition of dissolved cadmium nitrate solution into the ammonium molybdate solution with constant stirring for another 10 min. After complete addition, it was allow to stir for 15 more minutes with drop wise addition of dissolved thiourea, followed by stirring for 15 more minutes. The pH of the solution is measured to be 1. The solution was then transferred in teflon coated hydrothermal reactor and kept for 48 hours at 150 °C. After completion of reaction, reactor was allowed to cool down to room temperature naturally, followed by washing of the product with distilled water and filtered using 0.41 whatman filter paper. Further, products were washed using AR grade ethanol for several times and then dried at 80 °C for 4 hours in oven.

2.2 Photocatalytic Activity

2.2.1 H₂S Splitting

For photocatalytic studies, the cylindrical quartz reactor filled with 750 ml 0.25 M aqueous KOH. At room temperature, the vigorously stirred suspension was purged with argon for 1 h and then hydrogen sulphide (H₂S) generated in kipp's apparatus was bubbled through the solution for about 1 h. Each experiment was carried out in 750 ml of KOH solution (0.25

M) with H₂S flow 2.5 ml min⁻¹. The annealed MoS₂ and CdMoS₄ photocatalyst were introduced as a suspension into a reactor and irradiated with Xe-lamp light source (LOT ORIEL GRUPPE, EUROPA, LSH302, for Xe lamp spectrum) of intensity 300 W. The generated H₂ was collected in the graduated eudiometric tube. The purity of the collected gas was analyzed by gas chromatograph (Model Shimadzu GC-14B, MS-5 Å column, TCD, Ar carrier). Apparent quantum yield (QY) was determined with measuring intensity of light with Lux meter (Lutron LX-107HA) and it was placed in front of 300 W Xe light source to obtain the correct wavelength. Apparent quantum yield (AQE) was calculated according to the following equation:

$$\text{AQE (\%)} = \frac{\text{Number of H}_2 \text{ molecules evolved} \times 2}{\text{Number of incident photon}} \times 100$$

2.2.2 Water Splitting

The photocatalytic water splitting was carried out by using 100 ml double distilled water in 250 ml round bottom flask and 25 ml methanol as a sacrificial reagent. The annealed MoS₂ and CdMoS₄ catalyst was added with 1 wt% preloaded platinum as a co-catalyst. Argon gas was purged through this reaction mixture in order to remove the dissolved gases. The 250 ml round bottom flask was connected to the graduated measuring gas collector tube. The gas collector tube has septum arrangement to get rid of the evolved gas through the gas tight syringe for measure the amount of gas evolved. The all assembly was arranged in a wooden box and round bottom flask containing reaction mixture was irradiated with by 400 W mercury vapour lamp. The mercury vapour lamp was fitted with quartz condenser having arrangement for water circulation in order to absorb the IR radiation which minimizes the overheating effect. As soon as the lamp was switched on, the photocatalytic splitting of water was started and generated H₂ was collected in a graduated measuring gas collector. The amount of gas evolved was noted with time. The purity of the collected gas was analyzed by gas chromatograph (Model Shimadzu GC-14B, MS-5 Å column, TCD, Ar carrier).

2.3 Material Characterisation

The crystalline phases were investigated using X-ray powder diffraction (XRD) technique (XRD-D8, Advance, Bruker-AXS). Further, Cd, Mo and S content and oxidation state of element were examined using X-ray photoelectron spectroscopy (XPS, ESCA-3000, VG Scientific Ltd., England). Room temperature Raman spectroscopy were performed using a HR 800-Raman Spectroscopy, Horiba JobinYvon, France, with an excitation laser wavelength of 632.81 nm by a coherent He-Ne ion laser and a liquid nitrogen cooled detector to collect and process the scattered data. The optical properties of the powder samples were studied using an UV-visible-near infrared spectrometer (UV-VIS-NIR, Perkin Elmer Lambda-950). Photoluminescence properties of samples were analysed by using HORIBA Fluorolog 3 spectrofluorometer. The morphologies of the as synthesized and annealed sample were

investigated by field emission scanning electron microscopy (FESEM, Hitachi, S-4800). For TEM (JEOL, 2010F instrument). The visible light source used for the photocatalytic activity was Xe-lamp light source (LOT ORIEL GRUPPE, EUROPA, LSH302, for Xe lamp spectrum) of intensity 300 W. The purity of the collected gas was analyzed by gas chromatograph (Model Shimadzu GC-14B, MS-5 Å column, TCD, Ar carrier).

3. RESULTS AND DISCUSSION

The MoS₂ and CdMoS₄ nanostructures have been synthesized by facile solvothermal method. For the structural and phase comparison, the CdS has also been synthesized at an identical condition. The structural phase formation of as prepared CdS, MoS₂, CdMoS₄ and annealed CdMoS₄ and MoS₂ are investigated by X-ray Diffraction (XRD) and it is depicted in Figure 1a-d. The XRD of as prepared CdS, CdMoS₄ and MoS₂ are shown in Figure 1a. The XRD of as prepared CdS sample shows the formation of typical cubic structure, which matches very well with the reported JCPDS data card No. 01-075-1546. The XRD of as prepared MoS₂ shows the peaks at $2\theta=13.0^\circ$, 16.5° , 25.6° , 33.5° , 44.7° , 60.5° and 70.5° . After annealing the same sample at 400°C , depict slight shift in peak position from $2\theta=13.0^\circ$ to 13.8° (3hrs) and 14.0° (4 hrs) which indicates slight structural deformation in MoS₂ as shown in Figure 1c and which matches well with the reported hexagonal MoS₂ having JCPDS data card No. 00-009-0312. The as prepared CdMoS₄ is annealed at 400°C for 3 and 4 hours, respectively and their corresponding XRD were shown in Figure 1b. It is observed that the XRD peak at $2\theta=13^\circ$ in as prepared CdMoS₄ sample is slightly shifted to 13.5° and 14.0° after annealing at 400°C for 3 and 4 hours, respectively which indicates slight deformation in the crystal structure. It is observed that after annealing the samples, phase formation of MoS₂ and CdMoS₄ takes place which is confirmed by XRD and were depicted in Figure 1d along with as prepared CdS sample. The XRD of annealed CdMoS₄ sample has been analyzed using powder 4-DICVOLE-91 software, which shows the formation of monoclinic structure ($a=9.04588\text{ \AA}$, $b=4.01129\text{ \AA}$, $c=6.29441\text{ \AA}$ and $\beta=92.739^\circ$, $V=228.136\text{ (\AA}^3\text{)}$) and matches well with the reported literature.^{35,36}

The morphological investigations of the as synthesized CdS were performed by FESEM and were shown in ESI S-1 (Figure S-1a-d). From FESEM images, it is clearly observed that the formation of the cauliflower (1 μm) like morphology via assembling of tiny nanoparticles of size 10-15 nm. Figure 2a-d shows FESEM images of as prepared and annealed MoS₂, where one can clearly see the formation of long $\sim 5\text{ }\mu\text{m}$ mesoporous nanosheets with honeycomb like morphology. It is noteworthy that such unique honeycomb nanostructure of MoS₂ using solvothermal process is hitherto unattempted. Interestingly, the stacking of honeycomb sheets was also observed. Overall, we found the stacking of 2-3 sheets, occasionally. The thickness of sheet is observed to be $\sim 200\text{ nm}$ (See inset of Figure 2b). The thickness of the individual comb cell wall is observed to be $\sim 10\text{ nm}$ in size (Figure 2b,d). More

significantly, the cavities of honeycomb MoS₂ generated via vertical growth of nanosheets were also hexagonal in shape and the overall diameter of the cavities is around 40-50nm. The depths of the cavities were also measured to be 200 nm as per the layer thickness. Overall, FESEM observations depicts that there is not much change in the morphology of the as prepared and annealed MoS₂ sample.

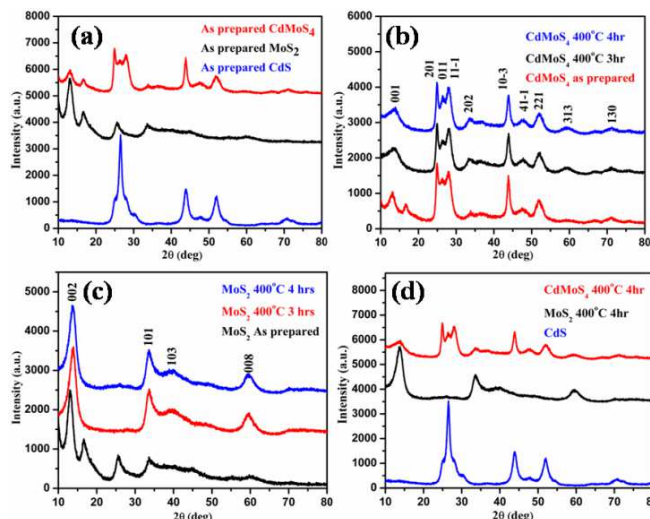


Figure 1. (a) XRD of as prepared CdS, CdMoS₄ and MoS₂. (b) XRD of CdMoS₄ as a function of annealing at 400°C for 3 hrs and 4 hrs. (c) XRD of MoS₂ as a function of annealing at 400°C for 3 hrs and 4 hrs. (d) XRD spectra of CdS and annealed CdMoS₄ and MoS₂.

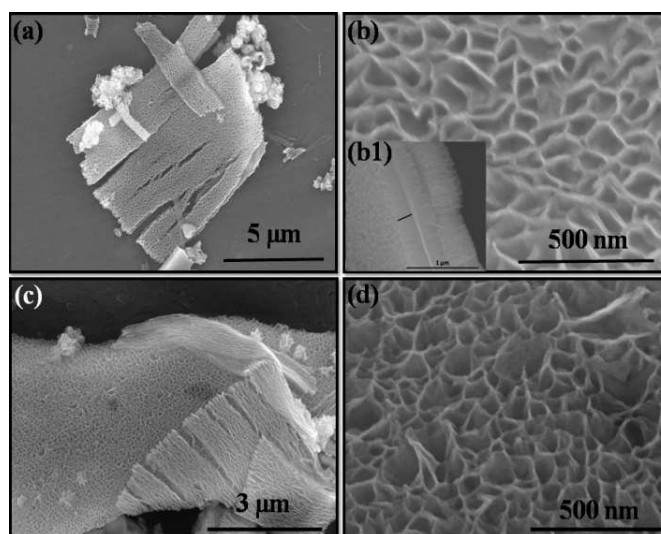


Figure 2. FESEM images of (a-b) as synthesized MoS₂ and (c-d) annealed MoS₂ at 400°C .

Further, the TEM investigations were performed in order to examine the morphology and crystalline nature of the annealed MoS₂ sample (Figure 3a-d). The hexagonal honeycombs like structure were also noticed in the TEM. The corresponding TEM images of annealed MoS₂ sample shows ordered mesoporous honeycomb structure with hexagonal cavities of 40-50 nm (Figure 3a), which is also in good agreement with our FESEM analysis. Figure 3a shows the High resolution (HR) TEM images taken from the edge of the nanosheets, which

provides more detailed structural information. The lattice spacing observed to be 0.266 nm which corresponds to the (002) plane of hexagonal MoS_2 (Figure 3c), and is in consistent with XRD results. Figure 3d shows the selected area electron diffraction (SAED) pattern of annealed MoS_2 sample which clearly shows a highly crystalline nature of sample attributed to the MoS_2 2H phase.

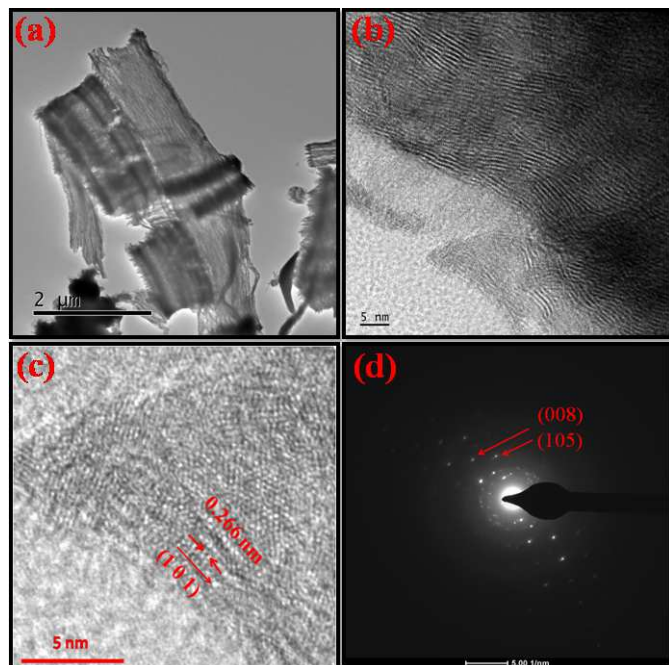


Figure 3. (a) Low resolution and (b, c) high resolution TEM images of annealed MoS_2 nanosheet sample at 400 °C and (d) corresponding SAED pattern.

The morphological investigations of as prepared and annealed CdMoS_4 sample were also carried out by FESEM. Figure 4 (a-b & c-d) shows the FESEM images of the as prepared and annealed CdMoS_4 sample, respectively. Further, FESEM results reveals the formation of porous marigold nanoflower like morphology. The magnified FESEM images (Figure 4b, d) indicate the detailed marigold nanoflower like structure instead of honeycomb which was observed in case of MoS_2 . Interestingly, marigold nanoflower like morphology composed of large number of thin nanopetals as building blocks. The as prepared CdMoS_4 sample (Figure 4a-b) shows compact flower like structure and annealed CdMoS_4 sample (Figure 4c-d) shows puffy nanoflowers. This is quite obvious that the modest growth in the petals is expected after annealing the sample. As expected, there are no much morphological changes in the size of the pore and flowers of CdMoS_4 . The average sizes of the hollow CdMoS_4 nanoflowers were observed to be in the range of 1.5-2 μm .

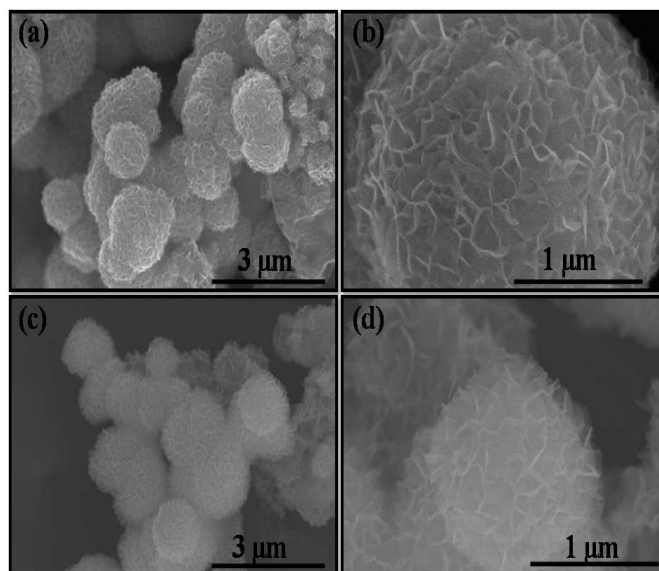


Figure 4. FESEM images of (a-b) as synthesized CdMoS_4 and (c-d) annealed CdMoS_4 at 400 °C.

The morphological and crystalline natures of the annealed CdMoS_4 samples were further characterized by TEM (Figure 5 a-d). The marigold nanoflower like structure is clearly seen in TEM images (Figure 5a-c). It is observed that nanoflower like structure obtained via self-assembling of thin curving petals. The morphology and size of the sample obtained from the TEM analysis matches well with the FESEM images depicted in Figure 4c-d. The Figure 5d shows the SAED pattern taken at the edge of the flakes shows the crystalline nature and monoclinic structure of the CdMoS_4 sample.

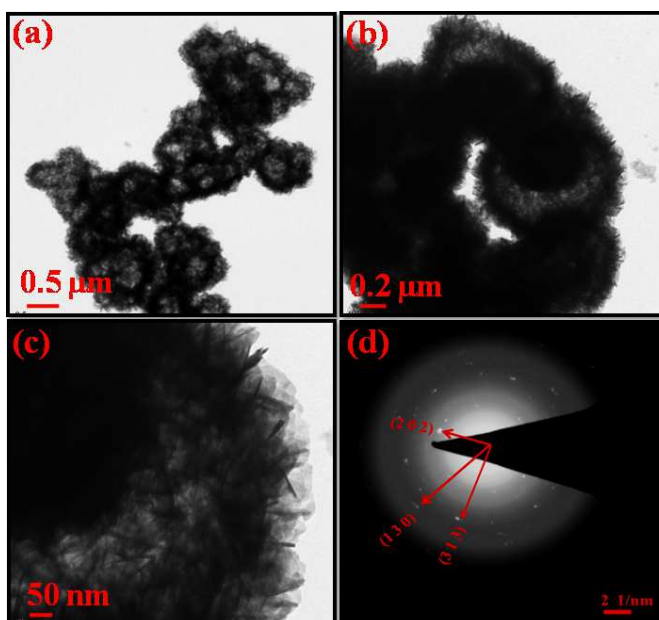


Figure 5. (a-c) TEM images and (d) SAED pattern of annealed CdMoS_4 at 400 °C nanoflower.

Further, the as synthesized and annealed samples were characterized using Raman spectroscopy. Raman spectroscopy is a very powerful and non-destructive technique widely used to

characterize various materials. It gives very precise and exact information about the change in bond distance and mechanical properties such as strain, stress, phase transition etc.³⁷⁻⁴⁰ In view of this, as prepared and annealed samples were characterized by Raman spectroscopy and are shown in Figure 6a-c. In case of CdS, intense and broad peak at ~ 302 , 603 and 903 cm^{-1} are assigned to fundamental optical phonon mode (LO) with the first overtone mode (2LO), and second overtone (3LO) of CdS, respectively (Figure 6c).⁴¹ In case of annealed MoS_2 , the Raman peaks at 382.5 and 406 cm^{-1} are identified as an E_{2g}^1 and A_{1g} vibration mode matches well with earlier reports (Figure 6a).⁴²⁻⁴³ These peaks belong to in-plane and out of plane vibration mode of typical MoS_2 sample. The width separation between two peaks is observed to be 23.5 cm^{-1} indicates the existence of few layer nature of MoS_2 which are also seen in FESEM (Figure 2). The other than E_{2g}^1 and A_{1g} vibration mode of annealed MoS_2 , new bands appeared in the as prepared MoS_2 phase which clearly shows the formation of 1T MoS_2 phase.⁴⁴ As synthesized 1T MoS_2 (octahedral geometry) is a metastable phase (not stable) and transformed to 2H structure (trigonal prismatic geometry) after annealing at 400 $^\circ\text{C}$ (Figure 6b).⁴⁵ The intense Raman peak at 298, 430, 598 and 960 cm^{-1} are assigned for as prepared CdMoS_4 sample which is shown in supporting information ESI S-2 (Figure S-1). Whereas, the peak at 125, 150, 182, 238, 285, 307, 398, 664, 754, 819, 860 and 890 cm^{-1} are assigned to annealed CdMoS_4 sample (Figure 6b). The Raman spectra of annealed CdMoS_4 sample do not show any signature of CdS or MoS_2 sample indicating the formation of single phase CdMoS_4 .

The XPS analysis of annealed CdMoS_4 sample was also carried out and which is observed to be good agreement with stoichiometric phase formation. The XPS were used to investigate the chemical state of Cd, Mo and S in the 400 $^\circ\text{C}$ annealed CdMoS_4 sample. The Cd 3d, Mo 3d and S2p spectra of these samples are shown in Figure 7a-c. The Cd spectra showed two peaks with binding energy values of 404.9 and 411.7eV, which corresponds to Cd 3d_{5/2} and Cd 3d_{3/2} core level peaks respectively as reported earlier.⁴⁶ Similarly, Mo also shows two peaks having binding energy values of 228.8 and 232.1eV assign to Mo 3d_{5/2} and Mo 3d_{3/2} core level peaks respectively, which were characteristic feature of the tetragonal $\text{Mo}^{+4}/\text{Mo}^{+6}$.⁴⁷⁻⁴⁹ Deconvolution of the XPS spectra by peak fitting revealed that the one Mo 3d doublets (228.4 and 229.1 eV) indicative of a mixed-valent (Mo^{4+} and Mo^{6+}) as shown in supporting information ESI: S-3 (Figure S-1a), which is in good agreement with earlier report.⁵⁰ Further, the area under curve reveal that percentage of Mo^{4+} and Mo^{6+} are found to be 37% and 63% respectively (for more details see supporting information ESI: S-3, Table S-1). The sulphur 2p spectra showed a peak at binding energy 161.6 eV, confirming the presence of sulfur.⁴⁶ Further, S2p peak deconvoluted into three peaks at binding energies 161.0, 161.6 and 162.4 eV assigned to CdS, MoS_2 and MoS_3 species (see supporting information ESI: S-3, Figure S-1b).^{47,51-52} Our XPS measurements established the formation of stable CdMoS_4 phase along with occasional CdMoS_{4-x} phase.

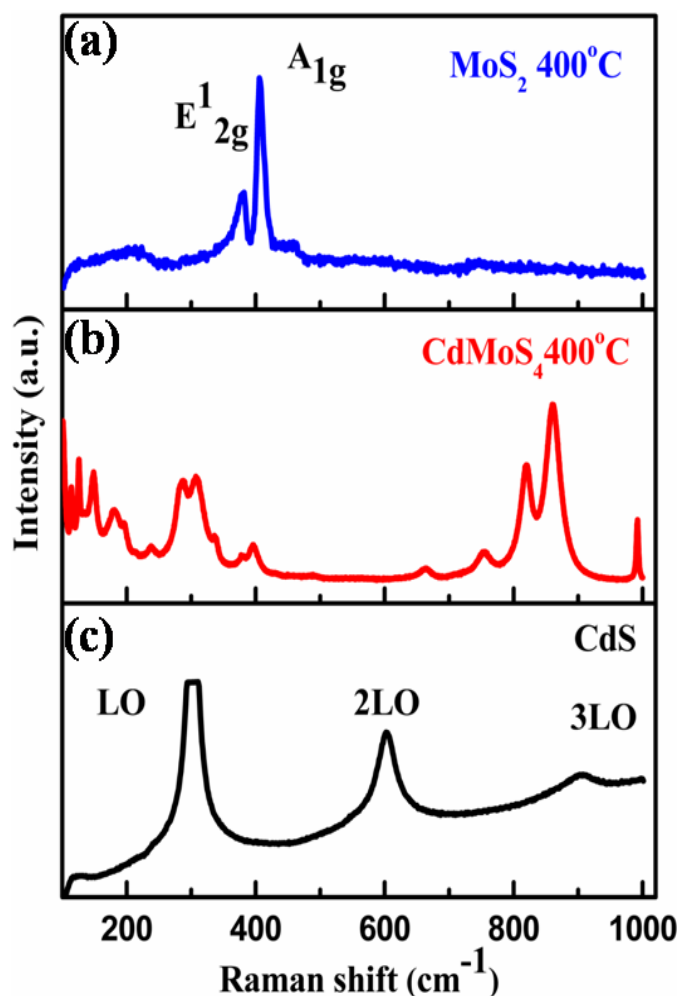


Figure 6. (a) Raman spectrum of as prepared CdS, (b) annealed CdMoS_4 and (c) annealed MoS_2 .

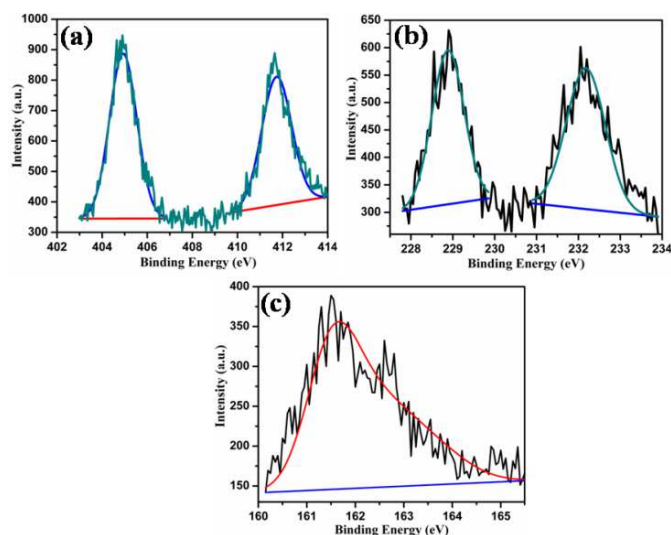


Figure 7. (a) Cd 3d, (b) Mo 3d and (c) S 2p XPS spectra of CdMoS_4 annealed at 400 $^\circ\text{C}$ samples.

The as synthesized CdS, MoS_2 , CdMoS_4 , and annealed MoS_2 , CdMoS_4 , samples were further characterized by UV-Vis spectroscopy as shown in Figure 8a-b. It is observed that the as

prepared CdS, MoS₂ and CdMoS₄ samples show the absorption edge cut off at ~510 (2.44 eV), 487 (2.55 eV) and 497 nm (2.50 eV), respectively. In case of annealed MoS₂ and CdMoS₄ (400 °C for 4 hrs), red shift in absorption edge has been observed. The annealed samples of MoS₂ and CdMoS₄ shows band gap of 1.6 and 1.5 eV respectively. In case of MoS₂, this may be due to decrease in the size and stacking of sheets and/or due to the structure transformation into 2H MoS₂.⁵³ It is quite obvious that CdMoS₄ may have such geometry as per the absorption behaviour.

The PL investigations are useful for analysis of migration, transfer, and recombination processes of photo induced electron-hole pairs in a semiconductor material. The room temperature PL spectra of the as synthesized and annealed samples were recorded with an excitation wavelength of 350 nm and are shown in Figure 8c,d. The CdS sample shows the broad emission peak at 630 nm and other low intensity shoulder peak shows at 644 nm. The strong orange emission obtained at 630 nm and other low intensity emission is attributed to the surface state defects or clustering of nanoparticles.⁵⁴⁻⁵⁶ In case of MoS₂ emission peak at 627 nm is due to the band edge transition which matches with earlier reports in literature.⁵⁷ The CdMoS₄ sample shows almost same intensity peak at 628 nm. The weak peak at 645 nm in CdMoS₄ sample is also due to the surface state defects.

The self-assemblies of 2D and 3D nanostructures have the predominant degree of clustering which also gives such weak broad peak. The intensity of PL emission peaks for MoS₂ and CdMoS₄ sample are much lower than that of CdS sample which indicates presence of more defects. This indicates that there is a great inhibition of electron (e⁻) and hole (h⁺) recombination in case of MoS₂ and CdMoS₄ sample.

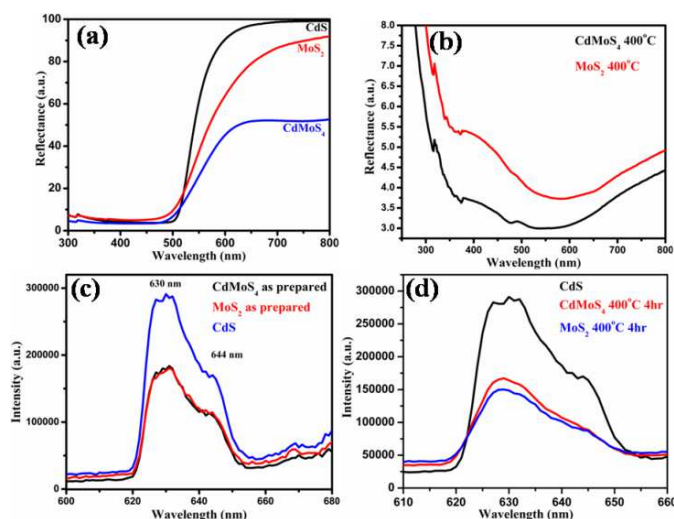


Figure 8. (a) Reflectance spectra of as synthesized CdS, CdMoS₄ and MoS₂. (b) Reflectance of CdMoS₄ and MoS₂ after annealing. (c) Photoluminescence spectra of as synthesized CdS, CdMoS₄ and MoS₂. (d) Photoluminescence spectra of as synthesized CdS, annealed CdMoS₄ and MoS₂ at 400 °C for 4 hours.

3.1 Formation mechanism of MoS₂ Nanosheet and CdMoS₄ nanoflower:

The MoS₂ nanosheets were prepared solvothermally using ammonium molybdate and thiourea in the methanol medium. During the solvothermal process, the ammonium ions and molybdenum ions are formed. Further these molybdate ions are reacting with thiourea and form MoS₄²⁻ ions as per the following reaction.⁵⁸



During the reaction the ammonium ions slowly decompose into NH₃ and H⁺ ions. These H⁺ ions are reacting with MoS₄²⁻ and gives 1T phase of MoS₂ as per the following reaction.⁵⁶



The as prepared MoS₂ nanosheet sample were 1T phase and it is observed that after annealing the sample at 400 °C, it transform to stable MoS₂ (2H phase) which has been discussed earlier in this manuscript.

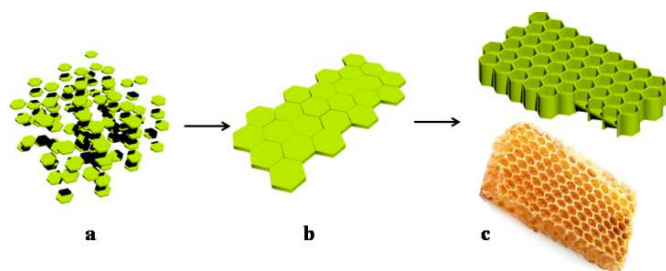
The CdMoS₄ samples were prepared using identical condition with cadmium nitrate as source material. The CdMoS₄ nanoflowers were formed proceeding through reaction (1) as per the following reaction.



The above as prepared CdMoS₄ nanoflower sample were annealed at 400 °C to confirm the formation of stable CdMoS₄ phase. Surprisingly, we did not observe any change in the surface morphology of as prepared and annealed MoS₂ and CdMoS₄ samples at 400 °C except puffiness of the nanoflowers in case of CdMoS₄.

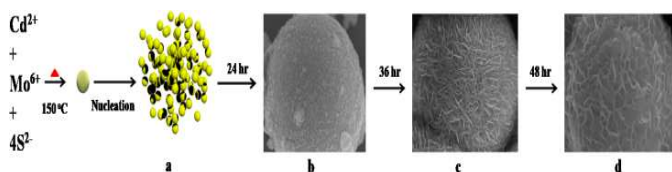
The schematic representation of growth mechanism for MoS₂ is shown in scheme 1. At hydrothermal condition, the MoS₄²⁻ ions are slowly reduced to form MoS₂. Primarily, the MoS₂ nuclei's in supersaturated solution are formed at hydrothermal conditions. These nuclei further grow and form the thin layered hexagonal nanoparticles by typical crystal growth mechanism *i.e.* Ostwald ripening process (Scheme 1a). Due to prolong hydrothermal reaction time, there is a 2D anisotropic growth of these thin hexagonal nanoparticles by oriental attachment and form a bigger thin layer MoS₂ sheets (Scheme 1b). Initially, the growth is quite faster due to the high concentration of MoS₂ nuclei and hence long sheets were formed. As hydrothermal reaction proceeds with time, the concentration of MoS₂ nuclei's in the reaction slows down, which confer the formation of smaller MoS₂ hexagonal cell with 2D vertical growth on bigger sheets (which also acts as a seed). Significantly, in the later stage of the hydrothermal reaction, the smaller vertically grown hexagonal thin nanosheets self-organized and form honeycomb like structure (Scheme 1c) with hexagonal cavity. This is a very unique structure obtained in this manuscript, not reported so far in the literature for the MoS₂. It is well known that such 2D growth and self-assembly is strongly related to the intrinsic structure of pristine MoS₂. Hence, honeycomb like structure with hexagonal cavity is quite justifiable. We observed that the stability of 1T

MoS₂ and as prepared CdMoS₄ is very poor as they immediately dissolved in slightly alkaline medium. However, annealed 2H MoS₂ sample are very stable in alkaline condition.



Scheme 1. Formation of Honeycomb structure of MoS₂. (a) Hexagonal nanosheets (b) monolayer of MoS₂ (c) MoS₂ Honeycombs.

The growth mechanism proposed for CdMoS₄ is somewhat similar but instead of honeycomb we obtained marigold nanoflower like structure. Initially, tiny nuclei of CdMoS₄ are generated as per the reaction (3) in the supersaturated solution and further growth of nanoparticles takes place with time (Scheme 2a). These newly formed nanoparticles are spontaneously aggregated to minimize their surface energy. These nanoparticles further grow anisotropically along the 3D directions and resulting in the formation of plane nanosphere of size 1.5 μm (Scheme 2b). At prolonged hydrothermal reaction, further growth is hindered due to the reduction in the precursor concentration. Hence, with prolong reaction time (36 hr), there is formation of slightly open nanoflower (scheme 2c). Whereas at 48 hr reaction time, there is formation of a 3D hierarchical nanostructure *i.e.* marigold nanoflowers. (Scheme 2d). Further, we studied the photocatalytic hydrogen evolution from H₂S using annealed MoS₂ and CdMoS₄ nanostructures.



Scheme 2. Formation of marigold flower of CdMoS₄. (a) CdMoS₄ NPT (b) self-assembled CdMoS₄ nanosphere (c) Slightly open CdMoS₄ nanosphere (4) CdMoS₄ Marigold nanoflower.

3.2 Photocatalytic study:

We performed photocatalytic activity for H₂ production from copious H₂S. Photocatalytic H₂ production experiments were conducted using as prepared CdS, MoS₂ and CdMoS₄ under visible light irradiation. Table 1 summarizes the results of photocatalytic activity for H₂ generation by photodecomposition of H₂S using as prepared CdS, annealed MoS₂ and CdMoS₄ nanostructure samples. The as prepared MoS₂ and CdMoS₄ sample did not show any photocatalytic activity due to the instability in alkaline medium. As discussed earlier, the structure of the as synthesized MoS₂ and CdMoS₄ itself is not stable and hence it gets degraded during the photocatalytic reaction. The annealed MoS₂ and CdMoS₄ show

superior and stable cyclic performance with ±0.1 % accuracy of activity due to the structural stability of these catalysts. It is important to note that all the experiments reported in this manuscript were carried out at an identical condition. The comparative time dependent photocatalytic H₂ production activities are shown in Fig. 9. The utmost H₂ production *i.e.* 10300, 12555 and 25445 μMole h⁻¹g⁻¹ were obtained for as prepared CdS, annealed MoS₂ and CdMoS₄, respectively. It is noteworthy that MoS₂ and CdMoS₄ sample have rendered significant photocatalytic activity, which is much higher than that of CdS samples reported in present work and previously reported nanostructures of CdS/CdS-MoS₂.^{25,32,59-61}

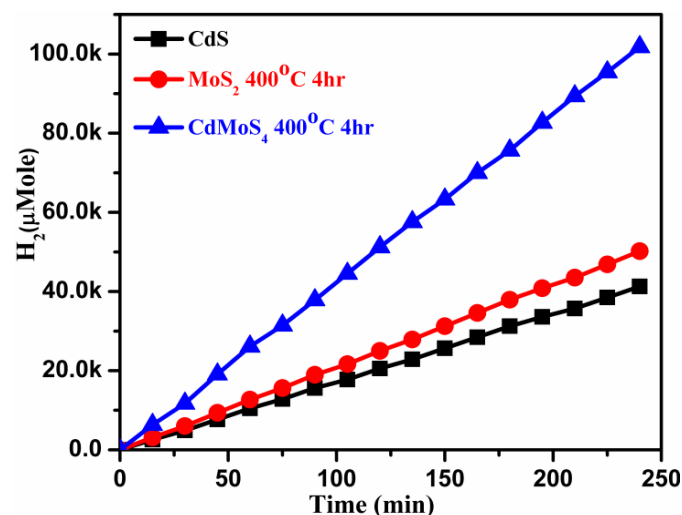


Figure 9. Photocatalytic H₂ generation activity plot by H₂S splitting for CdS, MoS₂ 400 °C and CdMoS₄ 400 °C.

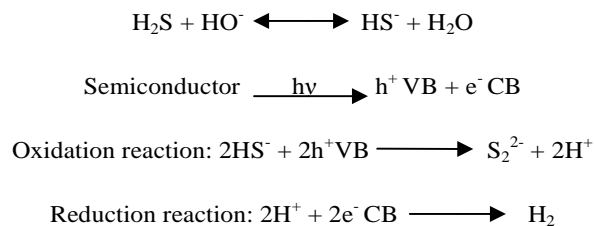
Table 1: Hydrogen generation from H₂S splitting.

Sr. No.	Catalyst used	Average H ₂ generated (μMole)	% Apparent quantum yield
1	CdS	10320	14.54
2	MoS ₂ 400 °C 4 hr	12555	17.68
3	CdMoS ₄ 400 °C 4 hr	25445	35.84

Considering the band gap of annealed MoS₂, CdMoS₄ and the as synthesized CdS, the higher activity obtained for CdMoS₄ is quite understood. Recently, Hinnemann *et al.* has demonstrated that MoS₂ nanostructure material is good photocatalyst for H₂ production.⁶² Additionally, the edge sites of MoS₂ and vacancy defects were found to be responsible for the photocatalytic activity.⁶³⁻⁶⁴ It is well known that the morphology of the material plays an crucial and important role in the context of photocatalysis.^{34,65-66} The FESEM and TEM image of the MoS₂ clearly shows the honeycomb like mesoporous structure. Further, the PL investigations, were also carried out which showed the vacancy defects in both the materials which ultimately suppress the recombination of photo

generated charge carrier, significantly. Hence, the enhanced photocatalytic H₂ production activity were obtained for the naked nanostructured MoS₂ (Honeycomb) is quite justifiable. Singh *et al.* has proved that MoS₂ nanosheet gives good H₂ evolution as compared to the bulk sample.⁵³ In the present case, we utilized few layers of MoS₂ nanosheets with honeycomb structure which has good stability along with short carrier diffusion time and hence shows good performance to photocatalytic activity for hydrogen production.⁶⁷ Additionally, for MoS₂ honeycomb structure (vertically grown hexagons) may be helping the fast transport of photo generated carriers to the surface which also responsible for enhanced H₂ production as compared to CdS. Interestingly, the CdMoS₄ nanoflower sample show almost double H₂ production performance as compared to CdS and MoS₂ sample. The previous reports of CdS and CdSe-MoS₂ hetero structure with 0.2 % MoS₂ shows good photocatalytic activity due to the inter electron transfer (CdS/MoS₂ composites).⁶⁸ However, it decreases with increasing MoS₂ concentration and reason for that is still unknown.⁶⁸ Interestingly, in the present case, single phase CdMoS₄ confer higher H₂ production activity with 35.84 % quantum efficiency. We propose that the morphology of the CdMoS₄ as compared with MoS₂ play the important role for enhanced H₂ production. Further, the morphology of CdMoS₄ is a porous marigold nanoflower like structure and we have demonstrated that the nanoflower like morphology confer good photocatalytic activity.³² The self-assembly of nanoflowers is from the thin petals which has more open surface area for absorption of light and hence produce more number of charge carriers. The electron transfer to the surface is quite easy due to the thin nanosheets or nanopetals like morphology of the sample which inhibit charge recombination. Interestingly, these nanoflowers are hollow and are observed to be highly crystalline in nature, which may also accountable for the enhanced photocatalytic activity.⁷ As discussed, flower like morphology (3D structure) has more advantage of fast electron transport to the surface as compared to Honeycomb structure. The vertically grown petals in honeycomb structure (2D structure) are accelerating electron transport to the surface but not fast as compared to 3D flower like structure. These structures have significance in the electron transport and mobility.³²

This is the only report which demonstrates the enhanced H₂ production by photocatalytic H₂S decomposition using CdMoS₄ nanoflower and honeycomb like MoS₂ nanostructure as a catalyst under visible light irradiation. The stability of the catalyst confirmed by performing recycles studies and which shows reproducibility of the results. The XRD of the reused sample catalyst did not depict any change in the phase purity of CdMoS₄ and MoS₂, which also indicates that the catalysts used for H₂ production are highly stable (see supporting information ESI S-4 Figure S1-S2). We did not found any H₂ production in the absence of catalyst and in the dark condition (without light). Overall, it is observed that the CdMoS₄ and MoS₂ samples are quite stable under the visible light and are acts as an active photocatalysts. The mechanism of hydrogen generation is explained as below:



The H₂S splitting under visible light takes place as follows. In 0.25 M KOH solution with pH 12.5 (pKa= 7.0) and the weak diprotic acid H₂S (pKa= 11.96) dissociates maintaining an equilibrium with HS⁻ ions. The CdMoS₄ and MoS₂ absorb the visible light and generate the e⁻ and h⁺. Due to the mesoporous structure, generated e⁻ and h⁺ easily goes to the surface of the catalyst and eagerly available for the photocatalytic activity. The photogenerated h⁺ from catalyst in valence band oxidizes the SH⁻ ion to proton (H⁺) and disulfide (S₂²⁻) ion. The photogenerated e⁻ in conduction band from the catalyst generates the molecular H₂ by reducing the H⁺. The reaction solution was always kept in the sulfide atmosphere by supplying the continuous bubbling of H₂S. The blank run without H₂S did not give any H₂ production indicates that H₂ production is from H₂S but not from water at similar experimental conditions.

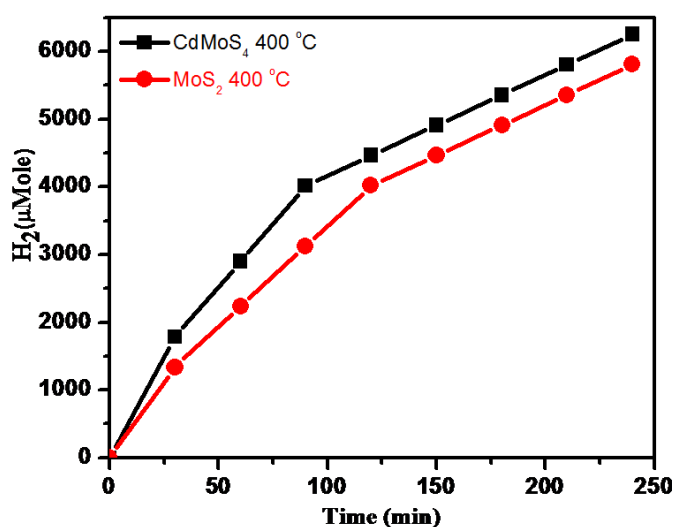


Figure 10 Photocatalytic H₂ generation from water with existence of sacrificial reagents using CdMoS₄ 400 °C and MoS₂ 400 °C.

Table 2: Hydrogen generation from H₂O splitting

Sr. No.	Catalyst used	Average H ₂ generated With Methanol (μMole)	Average H ₂ generated Without Methanol (μMole)
1	CdMoS ₄ 400 °C 4 hr	1562.5	919.1
2	MoS ₂ 400 °C 4 hr	1450.8	806

We have also attempted the water splitting experiment using 2D MoS₂ sheets and 3D CdMoS₄ nanoflower as an active

catalyst in the presence of UV-visible light. The highest H₂ production achieved by photocatalytic water splitting was 1562.5 and 1450.8 μMole h⁻¹g⁻¹ for CdMoS₄ and MoS₂, respectively. The time dependent H₂ production results were shown in Figure 10 and the H₂ production rate were given in Table 2. In the present investigations, we have used methanol as a sacrificial reagent. The methanol suppresses the evolution of oxygen through formation of free radicals. The photo-generated electron reduced the H⁺ ions to form H₂ gas while the hole react with water molecule to form ·OH radical. These ·OH radicals are reacting with CH₃OH and form ·CH₂OH and H₂O. The use of methanol as a sacrificial reagents and its mechanism is also discussed earlier by F. Guzman *et al.*⁶⁹ The hydrogen evolution without methanol as a scarifying agent was observed to be very low (See ESI:S-5, Figure S-1 and Table 2) which clearly indicates the significance of methanol. The low H₂ production rate for water splitting as compared to the H₂S is quite obvious due to the thermodynamics of water splitting. In nutshell, typically the morphology is responsible for the enhanced H₂ production. The MoS₂ has given comparable H₂ production because of the good photocatalytic ability for oxidation as well as reduction as reported earlier for few layered MoS₂.⁵³ We have demonstrated the detail investigation of the H₂ production from H₂S and attempted to compare with water splitting results. Overall, it is noteworthy that the MoS₂ honeycomb structure and newly design CdMoS₄ 3D marigold nanoflower demonstrates good H₂ production.

4. Conclusion

In conclusion, we have demonstrated the 2D honeycomb MoS₂ nanosheet and 3D nanostructure marigold flowers of CdMoS₄ with formation and growth mechanism. The annealing of samples at 400 °C confers very stable structures of (2H) MoS₂ and CdMoS₄ nanoflower. The photocatalytic H₂ production from H₂S and water splitting investigated for the annealed MoS₂ and CdMoS₄ samples. The CdMoS₄ exhibited enhanced H₂ production as compared to MoS₂, as the morphology of the catalysts plays an important key role in the enhancement of H₂ production. The generated e⁻ transfer to the surface is quite easy due to the thin nanosheets and nanopetals like morphology which inhibit charge recombination. Additionally, the surface defects generated by these nanostructures inhibit the charge carrier recombination. Our results open up several new avenues for utilization of MoS₂, CdMoS₄ and several other 2D layered TMDCs nanostructure materials for enhanced photocatalytic activity. The MoS₂ honeycomb like structure and newly design 3D CdMoS₄ marigold nanoflower will have potential to be used in other optoelectronic and energy harvesting devices.

Acknowledgements

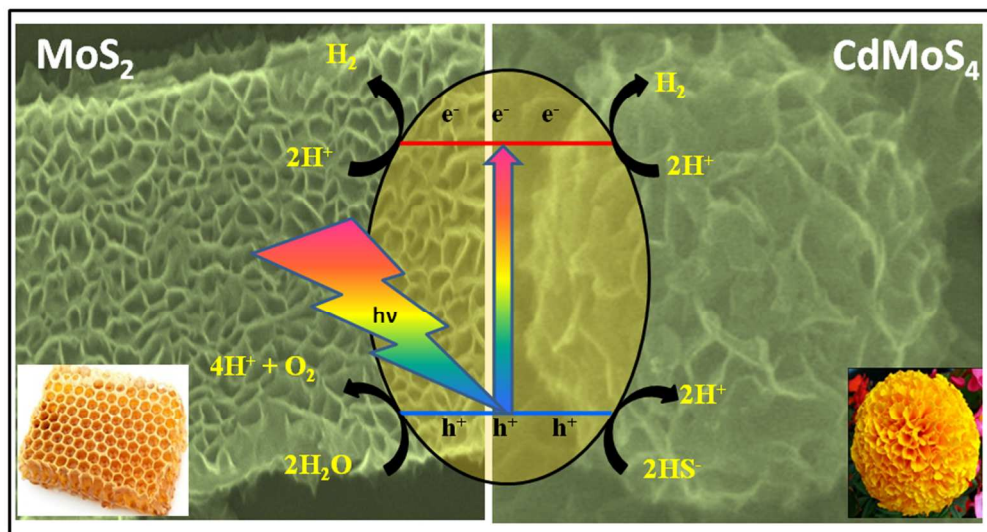
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Notes and references

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